

0.5-2.6GHz Si-Monolithic Wideband Amplifier IC (1985 [MWSYM])

T.-a. Nakata, S.-I. Miyazaki and K. Shirotori. "0.5-2.6GHz Si-Monolithic Wideband Amplifier IC (1985 [MWSYM])." 1985 MTT-S International Microwave Symposium Digest 85.1 (1985 [MWSYM]): 55-59.

Using Si, an excellent performances, 0.5-2.6GHz bandwidth and 23dB gain, monolithic wideband amplifier IC has been developed, of which input and output impedances are matched to 50 Ω . The f/sub T/=10GHz DNP-11 manufacturing process with optimization for microwave analog ICs has been developed for this IC. And a single-ended three stages circuit with local feedback adopted for this monolithic amplifier loops is circuit.

 [Return to main document.](#)